

## High Quality Audio

### J-FET Input Dual Operational Amplifier

#### ■GENERAL DESCRIPTION

The NJM8901 is a high quality audio dual operational Amplifier with JFET technology, strikes a balance between "MUSES technology" and mass-production technique.

The original process tuning and the assembly technology, based on MUSES technology, make excellent sound and absorbing cost increases.

The characteristics like Low noise ( $13\text{nV}/\sqrt{\text{Hz}}$ ), high slew rate ( $20\text{V}/\mu\text{s}$ ) and low distortion (0.003% at  $\text{Av}=10$ ) suitable for audio preamplifiers, active filters, and line amplifiers. In addition, taking advantage of the low input bias current that J-FET has, it is suitable for transimpedance amplifier (I/V converter).

#### ■FEATURES

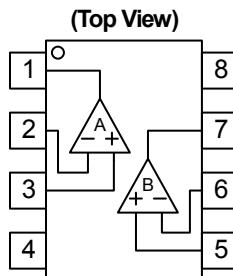
- Low Noise                             $13\text{nV}/\sqrt{\text{Hz}}$  typ.
- $1.6\text{uVrms}$  typ. (RIAA)
- Low Distortion                      0.003% typ. ( $\text{Av}=10$ )
- Wide Gain Bandwidth Product    5MHz typ.
- Slew Rate                             $20\text{V}/\mu\text{s}$  typ.
- Input Offset Voltage              2mV typ. 10mV max.
- Input Bias Current                 30pA typ. 400pA max.
- Open Loop Voltage Gain          110dB typ.
- Operating Voltage                  $\pm 4\text{V} \sim \pm 18\text{V}$
- J-FET Technology
- Package Outline                    SOP8 JEDEC 150 mil

#### ■PACKAGE OUTLINE



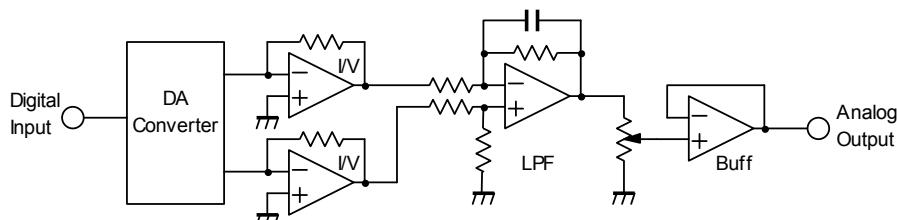
(SOP8 JEDEC 150 mil)

#### ■ PIN CONFIGURATION



- PIN FUNCTION**
- 1. A OUTPUT
  - 2. A -INPUT
  - 3. A +INPUT
  - 4. V-
  - 5. B +INPUT
  - 6. B -INPUT
  - 7. B OUTPUT
  - 8. V+

#### ■TYPICAL APPLICATION



DAC Output I/V converter + LPF circuit

# NJM8901

## ■ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V <sup>+</sup> /V <sup>-</sup>	±18	V
Common Mode Input Voltage Range	V <sub>ICM</sub>	±15 (Note1)	V
Differential Input Voltage Range	V <sub>ID</sub>	±30	V
Power Dissipation	P <sub>D</sub>	550 (Note2)	mW
Operating Temperature Range	T <sub>OPR</sub>	-40~+85	°C
Storage Temperature Range	T <sub>STG</sub>	-40~+125	°C

(Note 1) For supply Voltages less than ±15V, the maximum input voltage is equal to the Supply Voltage.

(Note 2) Mounted on the EIA/JEDEC standard board (114.3×76.2×1.6mm, two layer, FR-4).

Please refer to the following Power Dissipation and Ambient Temperature.

## ■RECOMMENDED OPERATING CONDITION (Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V <sup>+</sup> /V <sup>-</sup>		±4.0	-	±18	V

## ■ELECTRIC CHARACTERISTICS

### •DC CHARACTERISTICS (V<sup>+</sup>/V<sup>-</sup>=±15V, V<sub>cm</sub>=0V, Ta=25°C, unless otherwise noted.)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current	I <sub>CC</sub>	R <sub>L</sub> =∞, No Signal	-	4	6	mA
Input Offset Voltage	V <sub>IO</sub>	R <sub>S</sub> =50Ω (Note3)	-	2	10	mV
Input Bias Current	I <sub>B</sub>		-	30	400	pA
Input Offset Current	I <sub>IO</sub>	(Note3)	-	5	200	pA
Input Resistance	R <sub>IN</sub>		-	10 <sup>12</sup>	-	Ω
Large Signal Voltage Gain	A <sub>V</sub>	R <sub>L</sub> ≥2kΩ, V <sub>O</sub> =±10V	86	110	-	dB
Common Mode Rejection Ratio	CMR	V <sub>CM</sub> =±12V, R <sub>S</sub> ≤10kΩ	70	90	-	dB
Supply Voltage Rejection Ratio	SVR	V <sup>+</sup> /V <sup>-</sup> =±9.0 to ±18V, R <sub>S</sub> ≤10kΩ	76	100	-	dB
Maximum Output Voltage	V <sub>OM</sub>	R <sub>L</sub> ≥10kΩ	±12	+13.5, -13	-	V
Common Mode Input Voltage Range	V <sub>ICM</sub>	CMR≥70dB	±12	+15, -12.5	-	V

(Note3) Written by the absolute rate.

### •AC CHARACTERISTICS (V<sup>+</sup>/V<sup>-</sup>=±15V, V<sub>cm</sub>=0V, Ta=25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Slew Rate	SR	R <sub>L</sub> ≥2kΩ	-	20	-	V/us
Gain Bandwidth Product	GB	f=10kHz	-	5	-	MHz
Equivalent Input Noise Voltage1	e <sub>N</sub>	R <sub>S</sub> =100Ω, f=1KHz	-	13	-	nV/√Hz
Equivalent Input Noise Voltage2	V <sub>NN</sub>	RIAA, R <sub>S</sub> =2.2kΩ, 30kHz, LPF	-	1.6	3	μVrms
Total Harmonic Distortion	THD	f=1kHz, A <sub>V</sub> =+10, V <sub>O</sub> =5Vrms, R <sub>L</sub> =2kΩ	-	0.003	-	%
Channel Separation	CS	f=1kHz, A <sub>V</sub> =-100, R <sub>S</sub> =1kΩ, R <sub>L</sub> =2kΩ		130	-	dB

## ■Application Notes

### •Package Power, Power Dissipation and Output Power

IC is heated by own operation and possibly gets damage when the junction power exceeds the acceptable value called Power Dissipation  $P_D$ . The dependence  $P_D$  on ambient temperature is shown in Fig 1. The plots are depended on following two points. The first is  $P_D$  on ambient temperature 25°C, which is the maximum power dissipation. The second is 0W, which means that the IC cannot radiate any more. Conforming the maximum junction temperature  $T_{jmax}$  to the storage temperature  $T_{stg}$  derives this point. Fig.1 is drawn by connecting those points and conforming the  $P_D$  lower than 25°C to it on 25°C. The  $P_D$  is shown following formula as a function of the ambient temperature between those points.

$$\text{Dissipation Power } P_D = \frac{T_{jmax} - T_a}{\theta_{ja}} \text{ [W]} \quad (\text{Ta}=25^\circ\text{C} \text{ to } \text{Ta}=150^\circ\text{C})$$

Where,  $\theta_{ja}$  is heat thermal resistance which depends on parameters such as package material, frame material and so on. Therefore,  $P_D$  is different in each package.

While, the actual measurement of dissipation power on IC is obtained using following equation.

$$(\text{Actual Dissipation Power}) = (\text{Supply Voltage } V^+/\text{V}) \times (\text{Supply Current } I_{cc}) - (\text{Output Power } P_o)$$

This IC should be operated in lower than  $P_D$  of the actual dissipation power.

To sustain the steady state operation, take account of the Dissipation Power and thermal design.

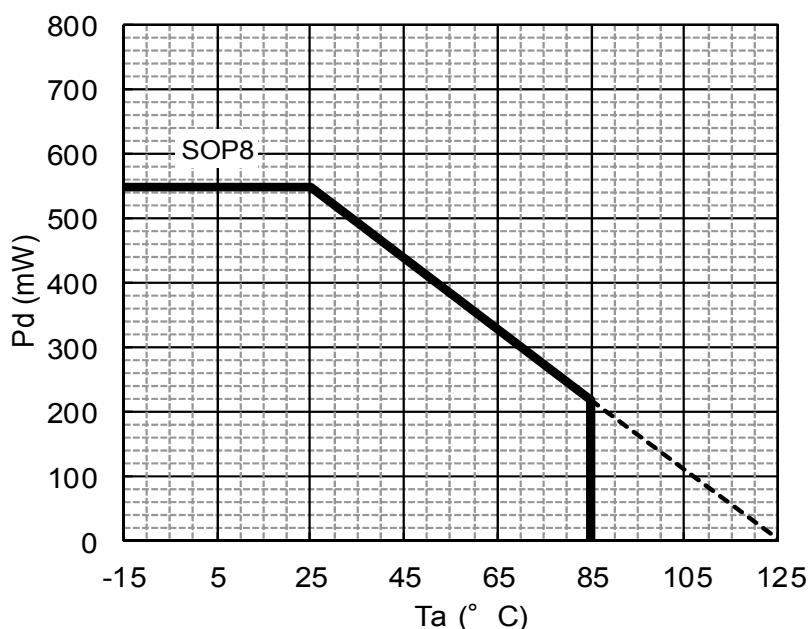
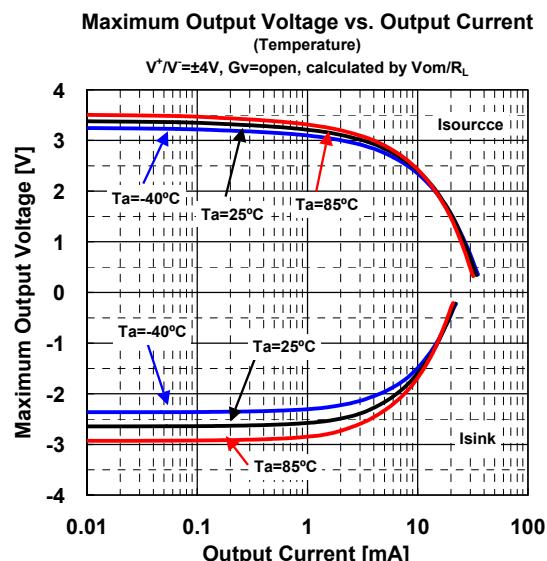
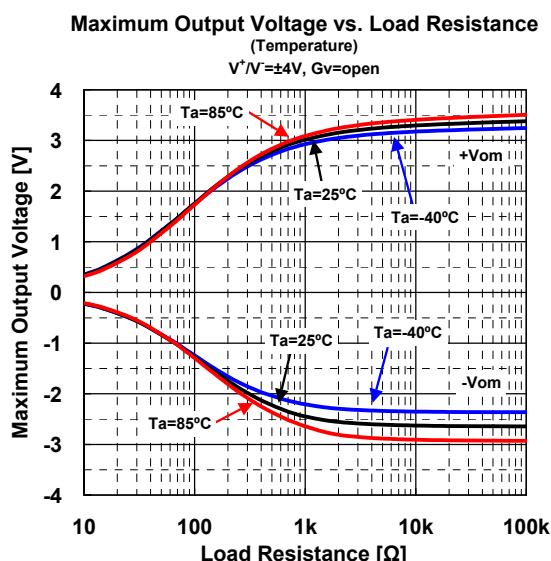
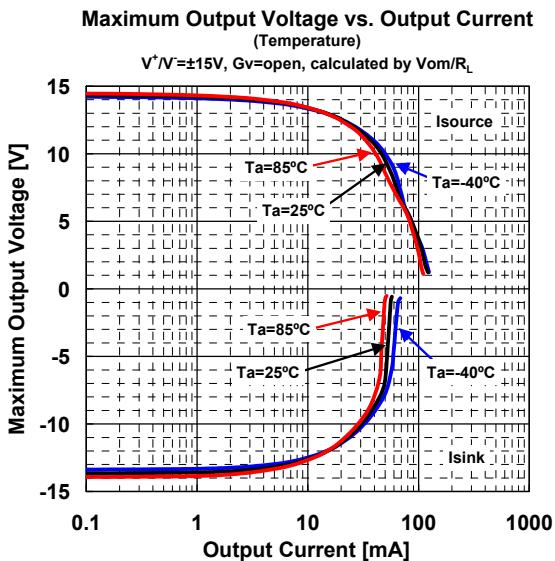
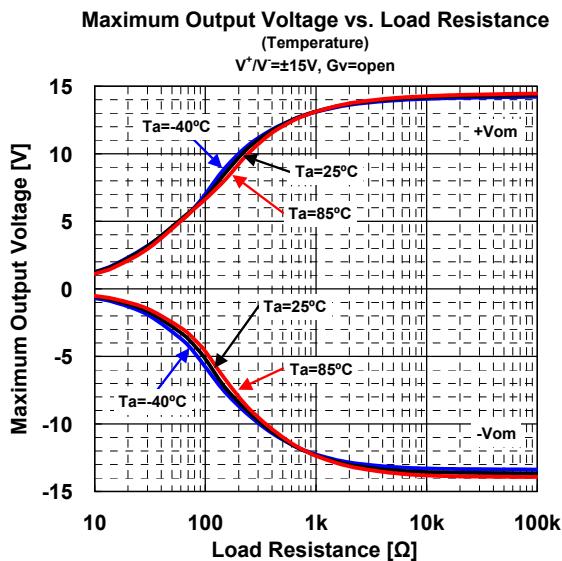
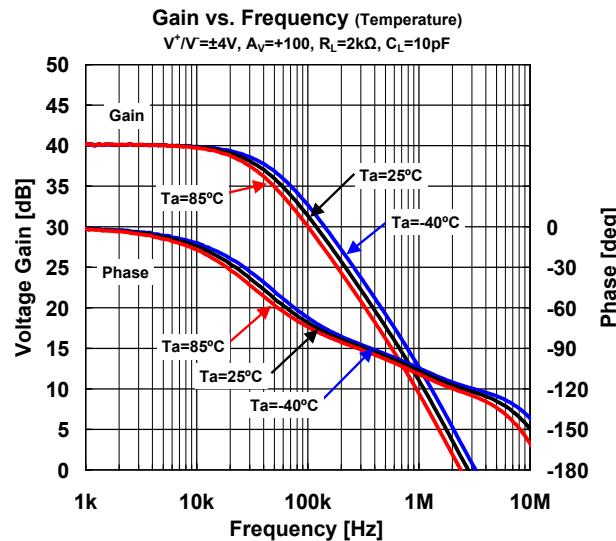
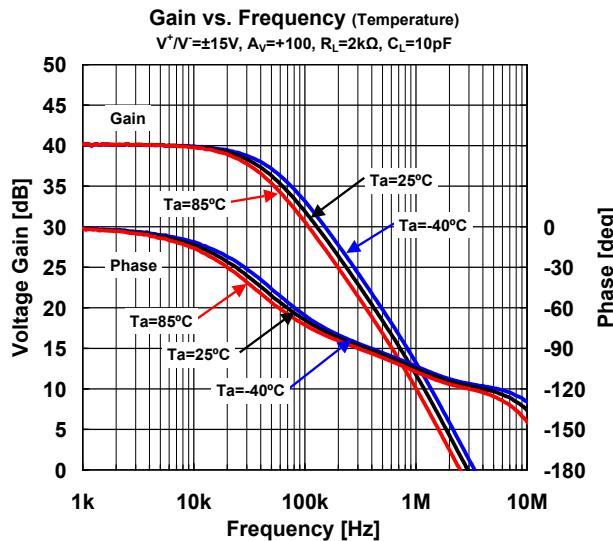


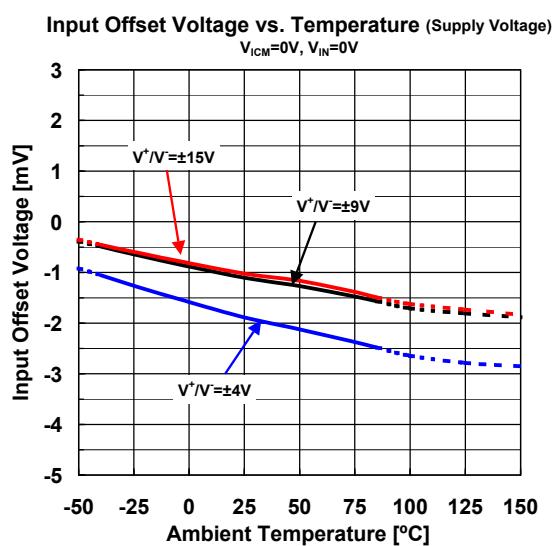
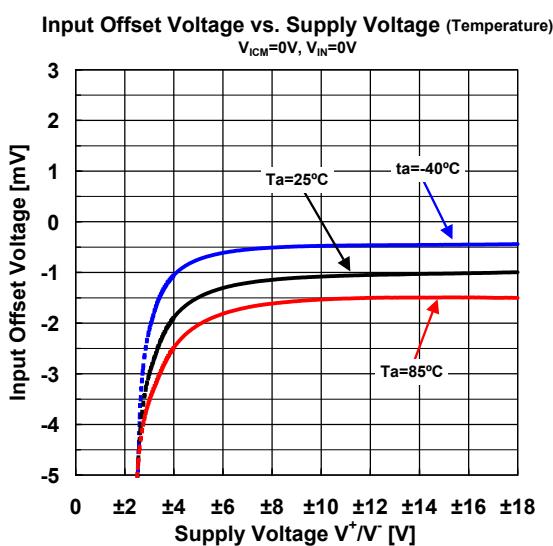
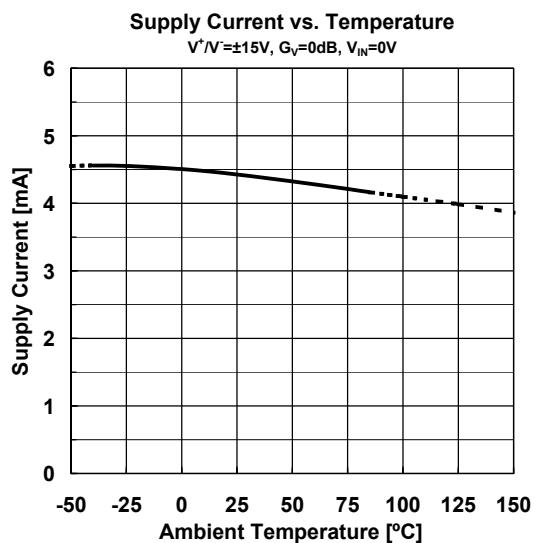
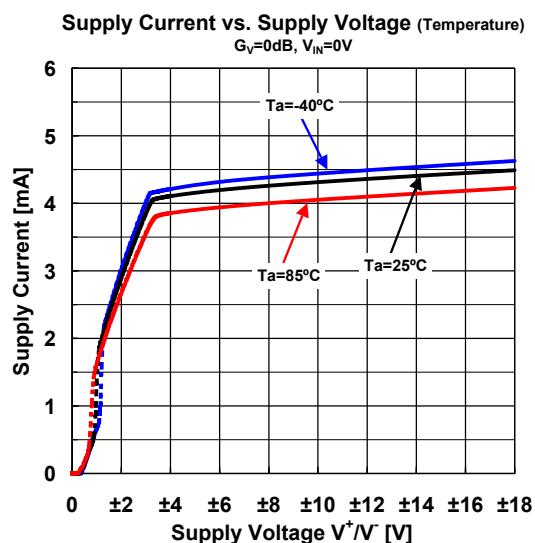
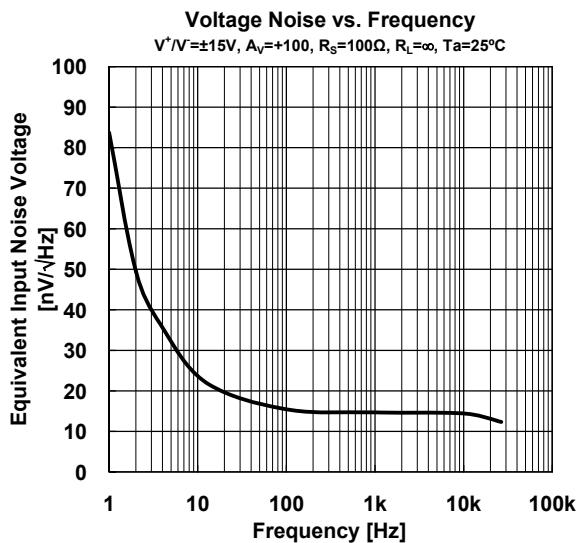
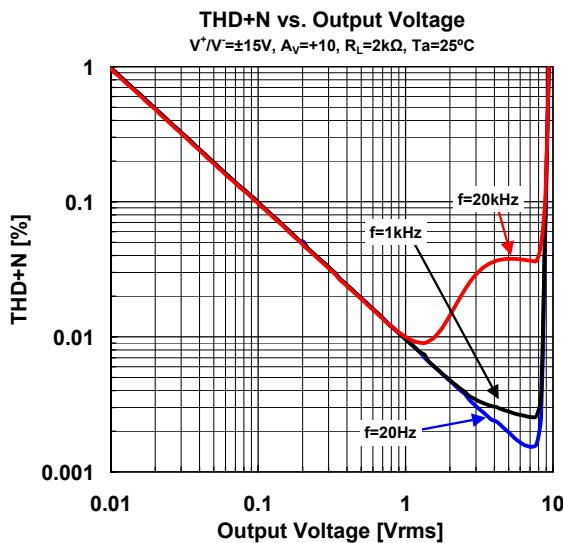
Fig.1 Power Dissipations vs. Ambient Temperature

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## ■ TYPICAL CHARACTERISTICS

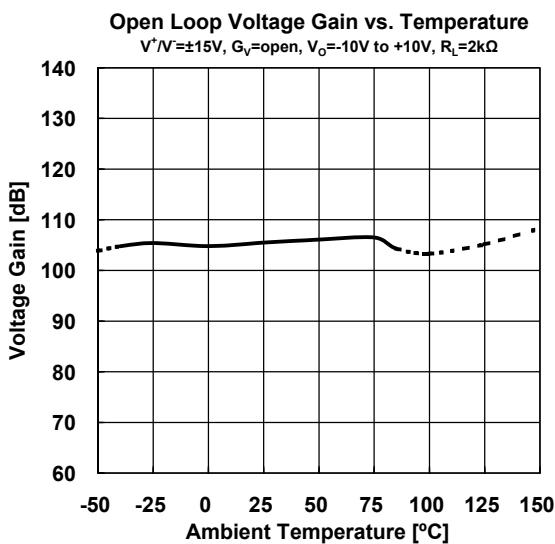
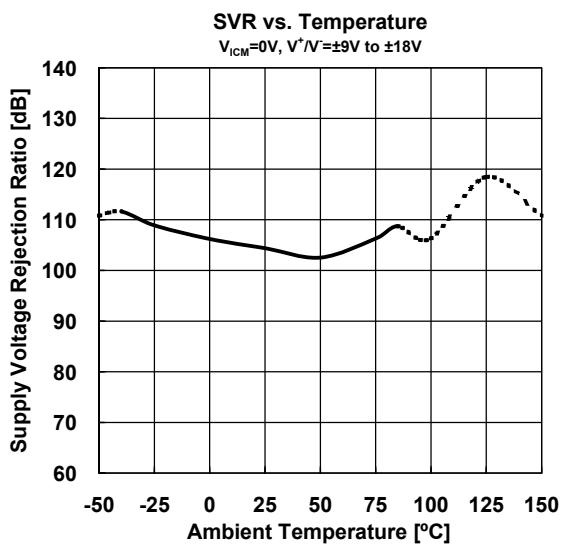
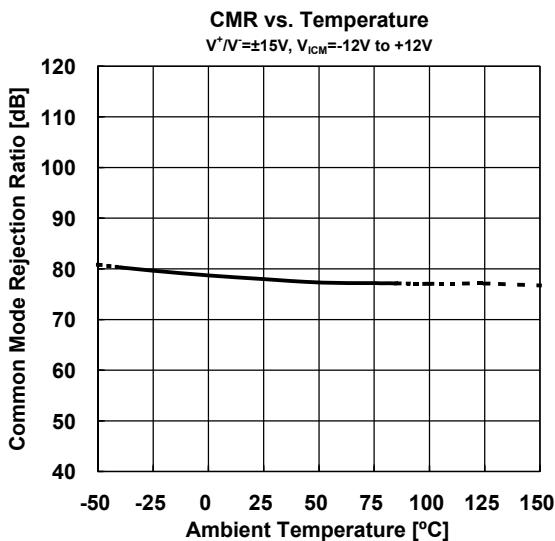
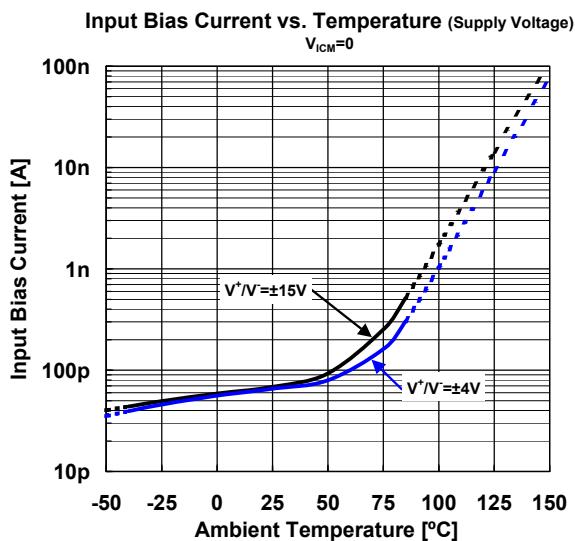
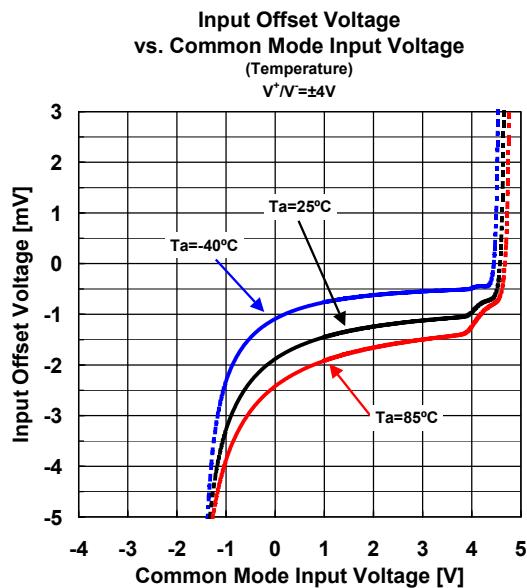
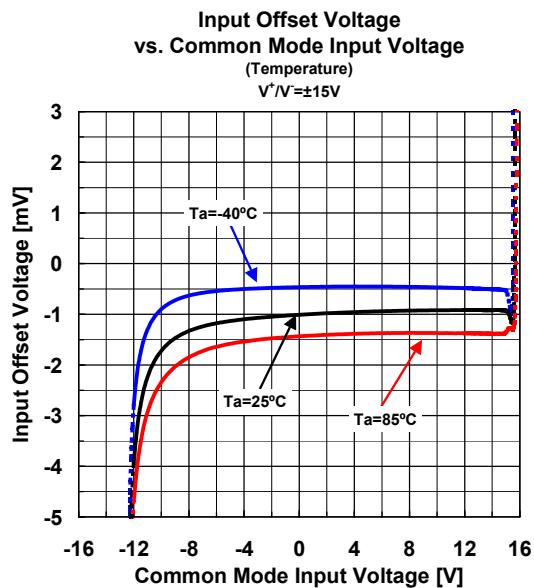


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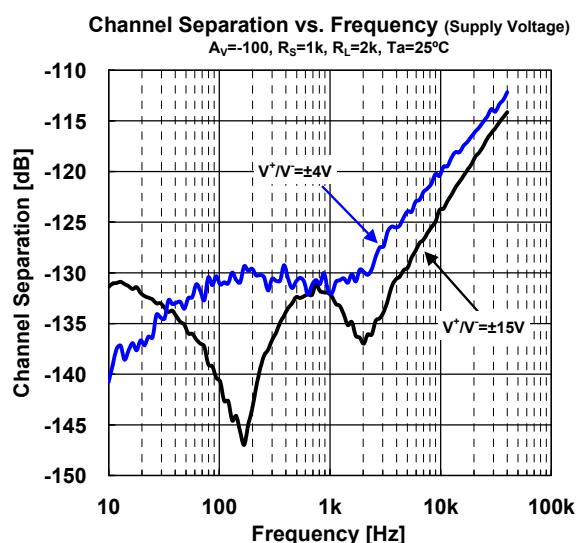
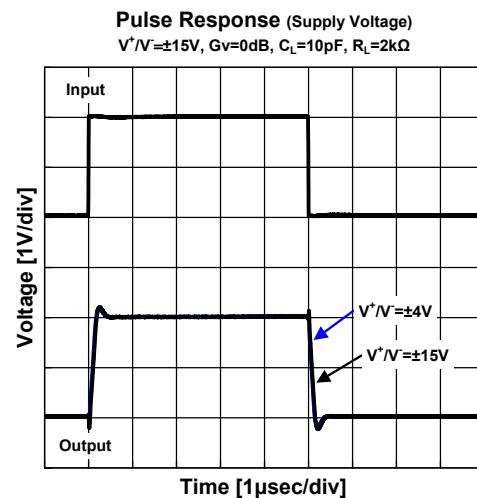
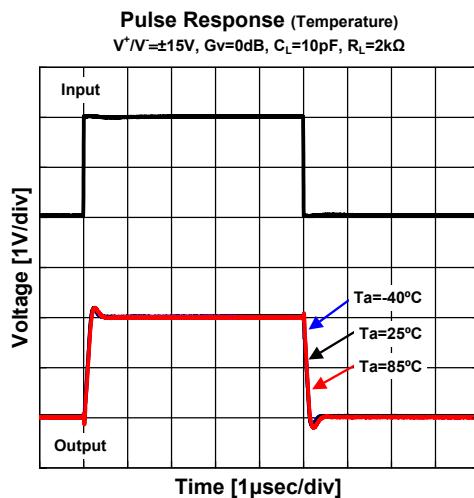


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